







Product Description

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The SGA2363Z is a high performance SiGe HBT MMIC Amplifier. A Darlington configuration featuring one-micron emitters provides high $F_{\rm T}$ and excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only two DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



Features

- High Gain: 16.1dB at 1950MHz
- Cascadable 50Ω
- Operates from Single Supply
- Low Thermal Resistance Package

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite

| Parameter | Specification | | | Unit | Condition | | |
|--|---------------|------|------|------|-----------------|--|--|
| Farameter | Min. | Тур. | Max. | Unit | Condition | | |
| Small Signal Gain | 15.8 | 17.5 | 19.3 | dB | 850MHz | | |
| | | 16.1 | | dB | 1950MHz | | |
| | | 15.6 | | dB | 2400MHz | | |
| Output Power at 1dB Compression | | 8.2 | | dBm | 850MHz | | |
| | | 7.2 | | dBm | 1950MHz | | |
| Output Third Intercept Point | | 19.4 | | dBm | 850MHz | | |
| | | 19.0 | | dBm | 1950MHz | | |
| Bandwidth Determined by Return Loss | | 5000 | | MHz | >10dB | | |
| Input Return Loss | | 15.1 | | dB | 1950MHz | | |
| Output Return Loss | | 25.5 | | dB | 1950MHz | | |
| Noise Figure | | 3.2 | | dB | 1950MHz | | |
| Device Operating Voltage | 2.4 | 2.7 | 3.0 | V | | | |
| Device Operating Current | 17 | 20 | 23 | mA | | | |
| Thermal Resistance | | 255 | | °C/W | junction - lead | | |

Test Conditions: $V_S = 5V$, $I_D = 20$ mA Typ., OIP₃ Tone Spacing=1MHz, P_{OUT} per tone=-5dBm, $R_{BIAS} = 120\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$

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SGA2363Z



Absolute Maximum Ratings

| 0 | | |
|--|------------|------|
| Parameter | Rating | Unit |
| Max Device Current (I _D) | 40 | mA |
| Max Device Voltage (V _D) | 5 | V |
| Max RF Input Power | +18 | dBm |
| Max Junction Temp (T _J) | +150 | °C |
| Operating Temp Range (T _L) | -40 to +85 | °C |
| Max Storage Temp | +150 | °C |
| | | |

Operation of this device beyond any one of these limits may cause permanent dam-age. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one. Bias Conditions should also satisfy the following expression:

 $I_D V_D < (T_J - T_L) / R_{TH}$, j-l

Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions no reaction of the device may reduce device reliability. Specified typical perfor-mance or functional operation of the device under Absolute Maximum Rating condi-tions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000 ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

Typical Performance at Key Operating Frequencies

| Parameter | Unit | 100 MHz | 500 MHz | 850MHz | 1950MHz | 2400 MHz | 3500 MHz |
|------------------------------------|------|---------|---------|--------|---------|----------|----------|
| Small Signal Gain | dB | 18.0 | 17.7 | 17.4 | 16.1 | 15.6 | 14.0 |
| Output Third Order Intercept Point | dBm | | 20.5 | 19.4 | 19.0 | 18.8 | |
| Output Power at 1dB Compression | dBm | | 8.2 | 8.2 | 7.2 | 6.8 | |
| Input Return Loss | dB | 18.2 | 17.0 | 16.2 | 15.1 | 13.3 | 11.6 |
| Output Return Loss | dB | 15.4 | 16.4 | 18.0 | 25.5 | 24.6 | 22.4 |
| Reverse Isolation | dB | 20.7 | 21.0 | 21.2 | 21.4 | 21.3 | 21.0 |
| Noise Figure | dB | | 2.9 | 2.9 | 3.2 | 3.5 | |

Test Conditions: $V_S = 5V$, $I_D = 20$ mA Typ., OIP₃ Tone Spacing = 1MHz, P_{OUT} per tone = -10dBm, $R_{BIAS} = 140\Omega$, $T_L = 25$ °C, $Z_S = Z_L = 50\Omega$



Typical RF Performance Over Temperature (Bias: $V_D = 2.7 V$, $I_D = 20 \text{ mA}$ (Typ.))







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| Pin | Function | Description |
|-------|-------------|--|
| 3 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. |
| 1, 2, | GND | Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible. |
| 4, 5 | | |
| 6 | RF OUT/BIAS | RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper oper- ation. |

SOT-363 PCB Pad Layout



We recommend 1 or 2 ounce copper. Measurements for this data sheet were made on a 31 mill thick Getek with 1 ounce copper on both sides.



SOT-363 Nominal Package Dimensions





Basic Application Circuit



| Reference | Frequency (Mhz) | | | | | |
|----------------|-----------------|--------|-------|-------|-------|--|
| Designator | 500 | 850 | 1950 | 2400 | 3500 | |
| C _B | 220 pF | 100 pF | 68 pF | 56 pF | 39 pF | |
| C _D | 100 pF | 68 pF | 22 pF | 22 pF | 15 pF | |
| L _c | 68 nH | 33 nH | 22 nH | 18 nH | 15 nH | |

| Recommended Bias Resistor Values for I_{D} =20mA R_{BIAS} =(V_{S} - V_{D}) / I_{D} | | | | |
|--|-----|-----|-----|------|
| Supply Voltage(V _s) | 5 V | 6 V | 8 V | 10 V |
| R _{BIAS} 120Ω 160Ω 270Ω 360Ω | | | | |
| Note: R _{BIAS} provides DC bias stability over temperature. | | | | |

Evaluation Board Layout



Mounting Instructions:

1. Use a large droung pad area near device pins 1, 2, 4, and 5 with plated through-holes as shown.

2. We recommend 1 or 2 ounces copper. Measurements for this data sheet were made on a 31mil thick FR-4 board with 1 ounce copper on both sides.



Part Identification Marking



Ordering Information

| Ordering Code | Description |
|---------------|---|
| SGA2363Z | 7" Reel with 3000 pieces |
| SGA2363ZSQ | Sample bag with 25 pieces |
| SGA2363ZSR | 7" Reel with 100 pieces |
| SGA2363ZPCK1 | 850MHz, 5V Operation PCBA with 5-piece sample bag |